Abstract—A high-performance dual-polarized eight-element air-filled substrate-integrated-waveguide (AFSIW) cavity-backed patch antenna array is presented. The antenna operates in the [26.5-29.5] GHz band and provides a stable high data-rate wireless communication link between end-user terminals and access points in next-generation cellular systems. Its topology is carefully selected to maximize the performance of the array. In addition, by combining the AFSIW technology with a new antenna architecture, a low-profile, low-cost, stable, and high-performance array design is guaranteed. A prototype was fabricated and validated, demonstrating a wide active impedance bandwidth over ±35° scanning range and low-cross polarization level within the entire frequency band.

Index Terms—Air-filled substrate-integrated-waveguide (AFSIW), aperture-coupled antenna, cavity-backed patch antenna, dual-polarized, 5G wireless communication, phased antenna array.

I. INTRODUCTION

The fifth-generation (5G) wireless communication systems will improve multiple key aspects of wireless communication to support the ever increasing demand for reliable and low-latency high-data rate mobile data traffic between end-user terminals and access points [1]. To address these stringent 5G goals, the next generation of wireless communication systems will exploit the large bandwidths available at millimeter wave (mmWave) bands [2], while adopting multi-antenna systems to leverage spatial multiplexing via highly directive communication links [3] and featuring ultra-dense deployment of small-cells [4].

In such a scenario, multiple short-range base stations (BSs) will be densely deployed using large-scale multi-antenna systems to precisely focus pencil-beams to end users. This will improve the cell border coverage and enhance the spectral efficiency and frequency reuse factor of the network. In addition, these pencil beams overcome the extremely challenging propagation conditions at the mmWave bands [5]. However, to achieve a broad market acceptance, these large-scale antenna systems need to be cost-effective, non-obstructive and low-weight. Moreover, they should provide beam scanning ability. Hence, there is a stringent need for innovative phased antenna architectures that support adaptive steering of directive beams.

In this paper, a wideband dual-polarized eight-element air-filled substrate-integrated-waveguide (AFSIW) cavity-backed patch antenna array covering the [26.5-29.5] GHz 5G band is presented. By an AFSIW implementation of the cavity, a low-loss low-cost antenna is obtained with highly efficient stable radiation characteristics and excellent antenna/platform isolation. A wideband antenna performance is achieved by exciting two hybrid modes. To exploit polarization diversity for reliable and low-latency high-data rate mobile data traffic between end-user terminals and access points, the antenna array consists of eight dual-polarized antenna elements that are rotated by 45°. A 70° scanning range for both polarizations is achieved. To the authors’ best knowledge, this is the first paper that describes an innovative highly-efficient low-cost dual-polarized AFSIW phased antenna array structure capable of steering highly directive beam for 5G cellular systems.

In recent years, multiple phased antenna arrays [6]–[9] have been proposed for 5G wireless communication systems. A single-polarized 4 x 8 antenna array composed of two 4 x 4 multilayer arrays is presented in [6]. About 25° beam steering is achieved in a bandwidth of [22 - 32] GHz with a gain of approximately 19 dBi. In [7], a multi-beam antenna composed of four single-polarized 1 x 4 multilayer SIW slot antenna arrays is designed. The antenna array can produce sixteen predefined sector beams with a gain of 14.5 dBi at 28 GHz. A single-polarized 64-element phased-array formed by a 2 x 2 transmit/receive beamformer chip is presented in [8] at 28 GHz. The phased array can scan up to ±50° in azimuth (H-plane) and ±25° in elevation (E-plane). An overview of some existing multibeam antenna technologies for 5G wireless communication is presented in [9].

This paper is organized as follows. In Section II, the topology and operation principle of the stand-alone antenna element is discussed. Moreover, the manufacturing process is explained in full detail, including a thorough corner analysis. Section III covers the design and construction of the 8 x 1 phased antenna array. In Section IV, a prototype of the antenna is validated. Conclusions and an outlook on future research are presented in Section V.
II. STAND-ALONE AFSIW ANTENNA ELEMENT

A. Antenna Design Tradeoffs

Large-scale highly-directive mmWave phased antenna arrays will play a key role in next-generation cellular mobile broadband communication systems. To guarantee peak performance of such a complex antenna system, the individual antenna element needs to be designed with utmost care and a challenging set of technical and economical requirements is imposed. Obviously, it should exhibit high and stable performance over a broad bandwidth in terms of radiation efficiency, half-power beamwidth and front-to-back ratio. Next, the proposed antenna topology needs to be compact to guarantee a broad grating-lobe-free scanning range. To facilitate integration with active electronics, it must be low-profile, while providing isolation between adjacent antenna elements. Moreover, fabrication cost and complexity have to be kept to the bare minimum to pave the way for deep market penetration. These tradeoffs make the design of an efficient mmWave-band antenna system without expensive multi-layer RF laminates and high-precision fabrication a real challenge.

The proposed wideband dual-linearly polarized aperture-coupled AFSIW cavity-backed patch antenna reconciles these conflicting demands in terms of performance, cost and footprint. In particular, following design requirements are imposed. The reflection coefficient with respect to $50 \, \Omega$ of each port should remain below -10 dB in the entire [26.5-29.5] GHz band, while guaranteeing an intra-element port-to-port isolation larger than 25 dB. In addition, the antenna element should exhibit a cross-polarization discrimination larger than 15 dB, a front-to-back ratio larger than 15 dB and a half-power beamwidth of more than 70° over the entire frequency band of operation. Finally, a radiation efficiency of more than 80% is required.

B. Principle of Operation

The proposed wideband dual-linearly polarized aperture-coupled AFSIW cavity-backed patch antenna is depicted in Fig. 1. A stacked AFSIW-based antenna technology is exploited to overcome the drawbacks of microstrip antennas (low efficiency and narrow bandwidth) while preserving the advantages of planar technology, being cost-effective fabrication, light weight and compact integration with monolithic microwave integrated components (MMICs), such as phase shifters and amplifiers. In addition, judiciously positioned rows of vias guarantee maximal suppression of surface waves and excellent antenna/platform isolation.

The stacked AFSIW antenna is composed of three layers: the radiating layer (Layer 1), the cavity layer (Layer 2) and the feed layer (Layer 3). The thickness and dielectric properties of each substrate are carefully chosen to achieve the required impedance bandwidth and a very high efficiency, while maintaining a small footprint and keeping back radiation and cost low. To obtain a wide impedance bandwidth and high efficiency, a circular radiating patch is printed on a thin low-permittivity substrate, forming Layer 1, and an air-filled cavity is introduced underneath the patch in Layer 2. To protect the patch from detrimental environmental effects, it is printed on the bottom side of its dielectric substrate. Next, the cavity sidewalls are realized in Layer 2 by rows of plated via holes, at locations that are very close to the edges of the air-cavity. This avoids that the electromagnetic fields penetrate substrate Layer 2 and minimizes mutual coupling between adjacent antenna elements. A small dielectric supporting region inside the cavity is preserved to guarantee sufficient mechanical strength. The design procedure described in [10] was leveraged to minimize loss and to obtain nearly substrate-independent behavior. As a result, a low-cost substrate material may be used to implement Layer 2 without compromising antenna performance. As shown in Fig. 1, the circular cavity-backed patch is fed by microstrip aperture coupling. Two perpendicular H-shaped apertures are used to maximize bandwidth and to excite two orthogonal linear polarizations, which can be used to generate circular polarizations in future designs. Leveraging aperture coupling also guarantees shielding between the antenna and the feed network, and contributes to radiation pattern purity. Back radiation is minimized by implementing the feed network on a thin low-loss dielectric substrate (Layer 3) and exploiting short-ended microstrip lines to excite the H-shaped apertures. Tuning is accomplished by trimming the short-circuited stub of the microstrip feed line and by adjusting the dimensions of the aperture. As shown in Fig. 1, MMICs can be compactly integrated on Layer 3 at the back of the antenna element.

The stand-alone antenna element was designed in two steps to ensure dual-linear polarization over a broad bandwidth. First, a single-feed single-polarized aperture-coupled AFSIW cavity-backed patch antenna topology was conceived such that two modes are excited at two neighboring frequencies. The mode at the lower frequency combines a weak $TM_{010, \text{cavity}}$ mode and a strong $TE_{11, \text{patch}}$ mode [Fig. 2(a)]. The mode at the higher frequency consists of strong $TM_{010, \text{cavity}}$ and $TE_{11, \text{patch}}$ modes [Fig. 2(b)]. By judiciously distributing both resonant frequencies over the frequency band of operation, the impedance bandwidth is increased significantly and the envisioned band is covered. To generate a second polarization, in the second and final step, a second feed line with H-shaped aperture is inserted by rotating the first feed line and aperture, and shifting it along the axis, as shown in Fig. 1. To provide
the same wideband performance for this second feed at second polarization state, the same modes are excited. At both resonant frequencies, a large electric field occurs across the antenna aperture, ensuring strong radiation in the hemisphere along the positive $z$--direction and weak radiation along the negative $z$--direction.

C. Manufacturing Process

The antenna has been optimized for high-performance mass production without using expensive multi-layer/thick RF PCB laminates. Therefore, in our design, only standard single layer PCB laminates were used to realize a cost-effective, broadband and modular solution. In particular, all layers (Layers 1-3) were fabricated by means of standard single layer PCB manufacturing technology at Eurocircuits [11]. The conductive parts of each layer were realized using a standard photolithography technique. A 0.508-mm-RO4350B substrate is exploited to construct Layer 1 and Layer 3 [Fig. 1]. Layer 2 is implemented in low-cost 1-mm-FR4 substrate. The air-filled cavity is implemented by milling out a cylinder with diameter $2b$, after which plated via holes (diameter $d$) are inserted around this air-filled region [Fig. 3(b)]. Finally, all layers are held together using 1-mm-diameter alignment pins and fixations [Fig. 1], to guarantee sufficient electrical contact and to provide correct alignment between layers. This allows a modular design, in which each part can be replaced later on with a different version.

Prior to the manufacturing, the antenna was optimized by using the frequency domain solver of CST Microwave Studio. Utmost care was taken to ensure that all design requirements, put forward in Section II.A, are met with sufficient margin, to account for variations in the material parameters and inaccuracies of the fabrication process. The antenna dimensions resulting from an extensive optimization process are shown in Fig. 3. The simulated magnitude of the reflection coefficients $|S_{11}|$ and $|S_{22}|$ are shown in Fig. 4(a). In the simulation, the S-parameters are normalized to 50 $\Omega$ impedance. Both exhibit two resonances distributed over the desired frequency band. The stand-alone antenna element features an impedance bandwidth of 6.5 GHz (or 23%) and 5.70 GHz (or 20%) for the vertical and horizontal polarization, respectively. Moreover, over the entire frequency band of operation, an isolation larger than 25 dB is guaranteed between both feeds, as shown in Fig. 4(a).

As shown in Fig. 4(c), the total antenna efficiency of the ultra-wideband dual-linearly polarized aperture-coupled AFSIW cavity-backed patch antenna is larger than 85% over the entire impedance bandwidth, with a maximum of 96%.

D. Analysis of Antenna Parameters

One of the key challenges of antenna design at high frequencies is coping with the manufacturing accuracy and tolerances, such as misalignment between layers and variations in antenna dimensions. Manufacturing errors need to be carefully considered from the early design stages to obtain a robust design. Hence, a systematic analysis of the antenna parameters was performed to understand the effects of manufacturing tolerances that are considered relevant for the topology.

In particular, several parameter sweeps were carried out to assess the influence of etching tolerances, misalignment, and
Fig. 4. Simulated stand-alone wideband dual-linearly polarized aperture-coupled AFSIW cavity-backed patch antenna performance. (a) S-parameters. (b) Maximum gain and back radiation: vertical polarization (dashed line) and horizontal polarizations (dash-dotted line). (c) Total antenna efficiency.

Fig. 5. Simulated S-parameters for variations on the antenna parameters. Assessing the influence of etching tolerances [±25 µm], misalignment [±100 µm], variations in material permittivity [±0.1], and thickness [±50 µm] on antenna performance: final design (full black line) and variations (full gray lines). (a) $|S_{11}|$. (b) $|S_{22}|$. (c) $|S_{21}|$. 
variations in material parameters (dielectric permittivity and thickness). Worst-case variations in the etching of the different metalization layers in the assembly are estimated to be ±25 µm and ±100 µm, respectively. The S-parameters were analyzed for misalignments of ±100 µm in the x− and y− directions, as well as along the first bisection.

Before analyzing the effect of variations in dielectric material parameters, the RO4350B and FR4 laminates’ electrical characteristics at 28 GHz were extracted by applying the matrix-pencil two-line method [12]. In the tolerance analysis, a deviation of 0.1 on the dielectric permittivity, being 3% for RO4350B and 2.3% for FR4, is considered. Finally, the influence of a dielectric thickness variation of ±50 µm on the S-parameters is analyzed.

Fig. 5 displays the simulated S-parameters for all previously discussed parameter sweeps. Based on this extensive parameter analysis, it can be concluded that the proposed design is sufficiently robust against fabrication errors and material variations.

### III. Antenna Array

Fig. 6 shows the exploded view of the proposed linear array. The array comprises eight dual-linearly polarized aperture-coupled AFSIW cavity-backed patch antenna elements. In the array, elements are rotated over 45° to achieve a higher signal-to-noise-ratio [13] and to provide a larger physical space for the compact integration of all required active MMICs.

The proposed array is designed for the frequency range of 26.5 to 29.5 GHz. An inter-element spacing of 6.4 mm (0.63λ at 29.5 GHz) was chosen to avoid grating lobes when scanning from -35° to +35°. The full array was designed in the frequency domain solver of CST Microwave Studio to validate the active reflection coefficient of the antenna element and to observe overall scanning performance of the array.

Fig. 7 shows the active reflection coefficient of one of the center antenna elements in the linear array for ±45° polarizations at 28 GHz, when the antenna array is steered in the YZ-plane. No scan blindness was found for both polarizations.

For both polarizations, the scanning performance of the array in the YZ-plane was examined. A uniform amplitude distribution is imposed. Fig. 8 shows the radiation patterns at 28 GHz for both polarizations, when scanning in the YZ-plane. A broadside array gain of 15.4 dBi is achieved without gain reduction when the array scans up to ±35°. Moreover, the radiation patterns for both polarizations demonstrate a grating-lobe-free beam scanning range up to ±35°. The half-power beamwidth amounts to 10.1° and 77° in the YZ-plane and XZ-plane, respectively. In this scanning range, the level of the side lobes remain below -12 dB.

### IV. Experimental Validation

To validate the proposed array topology, a stand-alone antenna element, depicted in Fig. 9, is initially fabricated and validated. In the manufacturing process, the ground plane of
Furthermore, the complete array will be manufactured and measured to verify the design. The results of these studies will be presented at the conference.

V. Conclusion

A new low-cost and low-profile dual-polarized aperture-coupled AFSIW cavity-backed patch antenna topology has been developed as an array element. The antenna covers all worldwide-planned 28 GHz 5G bands. Its measured radiation patterns, with a low level of cross-polarization, correspond well with the simulation results. The array element has optimal electrical dimensions to be deployed in a phased antenna array for beamsteering up to ±35°. The active impedance variations with respect to steering angle and scan performance of 8 x 1 linear array have been presented. The array exhibits stable radiation patterns within the complete steering range.

REFERENCES


